

# 58 series 1800V • 1a

(SiC MOSFET) PRELIMINARY



## AEC-Q101 Applying

### Specification

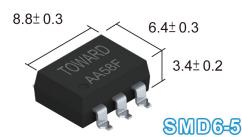
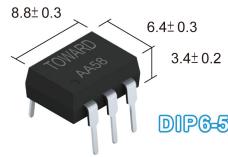
• Contact Form	1a
• Load Voltage	1800 V
• Operation LED Current	5.0 mA
• Load Current	50 mA
• On-Resistance	120 Ω
• Output Capacitance	80 pF
• Low Off-State Leakage Current	10 uA

### Application

- Battery Management System (BMS)
- Energy Storage System (ESS)
- Automatic Test Equipment (ATE)
- Telephone Equipment
- Security Equipment
- I/O Modules

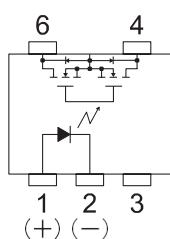
### Features

- High Voltage with Low On-Resistance
- Fast Reverse Recovery
- High Avalanche Ruggedness
- Steady Leakage Current at High Temperature



### Terminal Identification

#### AA58(F)



- 1:Anode (LED)  
2:Cathode (LED)  
3:NC  
4,6:Drain (MOSFET)

PART NO	PACKAGE	PACKING
AA58	DIP6-5	Tube 50pcs
AA58F	SMD6-5	Tube 50pcs
AA58F-R1	SMD6-5	Reel 1000pcs

## Absolute Maximum Ratings 絕對最大定格(Ambient Temperature 周圍溫度 : 25°C )

Item		Symbol	Value
Input 輸入	Continuous LED Current 連續LED 電流	I <sub>F</sub>	50mA
	Peak LED Current LED 峰值電流(f =100 Hz,Duty=1%)	I <sub>FP</sub>	500mA
	LED Reverse Voltage 逆向LED 電壓	V <sub>R</sub>	5V
	Input Power Dissipation 輸入損耗	P <sub>IN</sub>	75mW
output 輸出	Load Voltage 負荷電壓	V <sub>L</sub>	1800V (AC peak or DC)
	Load Current 負荷電流 (mA)	I <sub>L</sub>	50
	Peak Load Current 峰值負荷電流(1ms,1shot) (mA)	I <sub>PEAK</sub>	180
	Output Power Dissipation 輸出損耗 (mW)	P <sub>OUT</sub>	450
Total Power Dissipation 全損耗 (mW)		P <sub>T</sub>	500
I/O Breakdown Voltage 輸入/出力間絕緣電壓 (Vrms)		V <sub>I/O</sub>	3750
I/O Breakdown Voltage 輸入/出力間絕緣電壓(Suffix-H) (Vrms)		V <sub>I/O</sub>	5000
Operating Temperature 使用時溫度		T <sub>OPR</sub>	-40°C ~ +85°C
Storage Temperature 保存溫度		T <sub>STG</sub>	-40°C ~ +100°C

## Electrical Specifications 電性規格 (Ambient Temperature 周圍溫度 : 25°C )

Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input 輸入	LED Forward Voltage LED 順向電壓	V <sub>F</sub>	1.0	1.33	1.5	V	I <sub>F</sub> =10mA
	Operation LED Current LED 動作電流	I <sub>FON</sub>		2.0	5.0	mA	
	Recovery LED Voltage LED 復位電壓	V <sub>F OFF</sub>	0.5	1.2		V	
Output 輸出	On-Resistance 導通電阻 Drain to Drain	R <sub>ON</sub>		80	150	Ω	I <sub>F</sub> =10mA,I <sub>L</sub> =Rating
				120	200	Ω	I <sub>F</sub> =10mA,I <sub>L</sub> =5 mA
	Off-State Leakage Current *1 開路狀態漏電流(註1)	I <sub>LEAK</sub>		10	μA	V <sub>L</sub> =1800V	
Transmission 傳達	Output Capacitance 輸出端容量	C <sub>OUT</sub>		80		pF	V <sub>L</sub> =0V,f=1MHz
	Turn-On Time 動作時間	T <sub>ON</sub>		0.5	3.0	ms	I <sub>F</sub> =10mA,I <sub>L</sub> =Rating
Coupled 結合	Turn-Off Time 復位時間	T <sub>OFF</sub>		0.15	1.0	ms	
	I/O Insulation Resistance 輸入/出間絕緣阻抗	R <sub>I/O</sub>	10 <sup>10</sup>			Ω	
	I/O Capacitance 輸入/力端靜電容量	C <sub>I/O</sub>		1.3		pF	f=1MHz

Note \*1 : The leakage current value is for 25 degree C. If need more detailed information, please contact your local sales representative.